

### Takahashi et al.

### [54] LIGHT VALVE DEVICE USING SEMICONDUCTIVE COMPOSITE SUBSTRATE

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[57]

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### ABSTRACT

A semiconductor device having a double-side wiring structure, in which a single crystal semiconductor thin film is formed integrally with transistor elements and is laminated on an insulating thin film. The single crystal semiconductor thin film is formed with through-holes and the insulating thin film is formed on its back side with electrodes and a shielding film. A light valve device using the semiconductor device is also disclosed. Over the single crystal semiconductor thin film, there are formed switching elements of transistors, pixel electrodes connected electrically with the switching elements, and drive circuits for scanning and driving the switching elements. Also disclosed is a miniature highly dense light valve device. In this light valve device, an electrooptical substance is arranged between a multilayer substrate. The multi-layer substrate is formed with electrodes and a shielding film at the opposed side of the insulating film to the side formed with the grouped elements through the insulating film. A transparent opposite substrate is also formed so that the optical transparency of the electrooptical substance is controlled by the switching elements.

### 25 Claims, 19 Drawing Sheets





FIG. 2 PRIOR ART



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FIG. 3



FIG. 4(a)



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R

М



FIG. 5



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Α

R

М



FIG. 7



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